

L Number	Hits	Search Text	DB	Time stamp
1	3817	((257/355-358) or (257/360-363) or (361/56,111)).CCLS.	USPAT; US-PGPUB	2003/11/19 15:02
2	171	((257/173,355-358,360-363) or (361/56,111)).CCLS.) and @pd > "20030619"	USPAT; US-PGPUB	2003/11/19 15:05
3	107	((257/173,355-358,360-363) or (361/56,111)).CCLS.) and @pd > "20030619" and (esd electrostatic adj discharge)	USPAT; US-PGPUB	2003/11/19 15:06
4	3	(reverse adj breakdown) and (breakdown near3 gate adj (oxide insulator)) and @pd > "20030619"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/19 15:06
5	79	reverse adj breakdown and @pd > "20030619"	USPAT; US-PGPUB	2003/11/19 15:07
6	369	protection with diode and @pd > "20030619"	USPAT; US-PGPUB	2003/11/19 15:07
7	77	breakdown near3 gate adj (oxide insulator) and @pd > "20030619"	USPAT; US-PGPUB	2003/11/19 15:07
8	2	core adj region and I/O adj region and @pd > "20030619"	USPAT; US-PGPUB	2003/11/19 15:08
9	92	protection with diode and cmos and @pd > "20030619"	USPAT; US-PGPUB	2003/11/19 15:09
10	183	input adj pad and @pd > "20030619"	USPAT; US-PGPUB	2003/11/19 15:08
11	14	((reverse adj breakdown) and input) and (protection with diode) and @pd > "20030619"	USPAT; US-PGPUB	2003/11/19 15:09
12	1	(protection with diode and cmos) and core adj region	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/19 15:09
13	107	((257/173,355-358,360-363) or (361/56,111)).CCLS.) and @pd > "20030113" and (esd electrostatic adj discharge) and @pd > "20030619"	USPAT; US-PGPUB	2003/11/19 15:10